

Trench IGBT Modules

SEMiX603GB12E4pV1

Features*

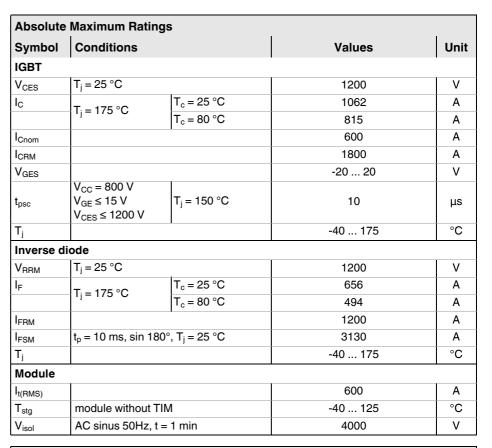
- · Homogeneous Si
- Trench = Trenchgate technology
- V_{CE(sat)} with positive temperature coefficient
- High short circuit capability
- Press-fit pins as auxiliary contacts
- Thermally optimized ceramic
- UL recognized, file no. E63532

Typical Applications

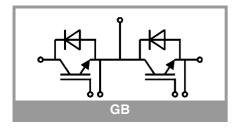
- · AC inverter drives
- UPS
- Renewable energy systems

Remarks

- Product reliability results are valid for T_j=150°C
- V_{isol} between temperature sensor and power section is only 2500V
- For storage and case temperature with TIM see document "TP(*) SEMiX 3p"



Characteristics									
Symbol	Conditions	min.	typ.	max.	Unit				
IGBT	•					•			
V _{CE(sat)}	$I_C = 600 \text{ A}$ $V_{GE} = 15 \text{ V}$ chiplevel	T _j = 25 °C		1.80	2.05	V			
		T _j = 150 °C		2.03	2.30	V			
V _{CE0}	chiplevel	T _j = 25 °C		0.87	1.01	V			
		T _j = 150 °C		0.77	0.90	V			
r _{CE}	GL -	T _j = 25 °C		1.55	1.73	mΩ			
		T _j = 150 °C		2.1	2.3	mΩ			
$V_{GE(th)}$	$V_{GE} = V_{CE}$, $I_{C} = 22.2$ mA		5.1	5.8	6.3	V			
I _{CES}	$V_{GE} = 0 \text{ V}, V_{CE} = 12$			5	mA				
C _{ies}	V _{CE} = 25 V V _{GE} = 0 V	f = 1 MHz		37.5		nF			
Coes		f = 1 MHz		2.31		nF			
C _{res}		f = 1 MHz		2.04		nF			
Q_G	V _{GE} = -8 V+ 15 V T _j = 25 °C			3450		nC			
R _{Gint}				1.2		Ω			
t _{d(on)}	$\begin{array}{l} I_{C} = 600 \text{ A} \\ V_{GE} = +15/\text{-}15 \text{ V} \\ R_{G \text{ on}} = 1.5 \Omega \\ R_{G \text{ off}} = 1.5 \Omega \\ \text{di/dt}_{on} = 6500 \text{ A/}\mu\text{s} \\ \text{di/dt}_{off} = 3800 \text{ A/}\mu\text{s} \end{array}$	T _j = 150 °C		170		ns			
t _r		T _j = 150 °C		80		ns			
Eon		T _j = 150 °C		58		mJ			
t _{d(off)}		T _j = 150 °C		530		ns			
t _f		T _j = 150 °C		130		ns			
E _{off}		T _j = 150 °C		80		mJ			
R _{th(j-c)}	per IGBT				0.04	K/W			
R _{th(c-s)}	per IGBT (λ _{grease} =0.81 W/(m*K))			0.035		K/W			
R _{th(c-s)}	per IGBT, pre-appli material		0.025		K/W				





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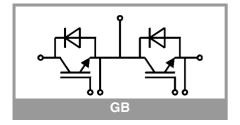
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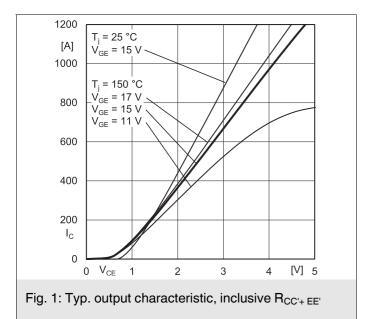
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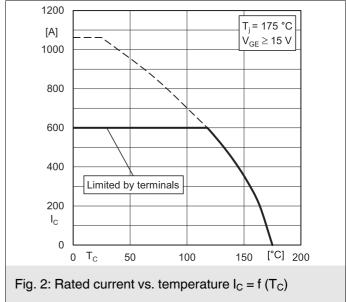
Remarks

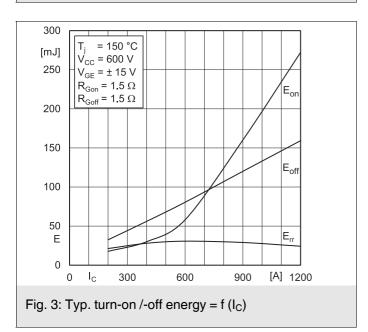
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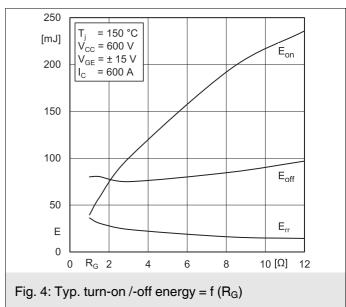
Characteristics										
Symbol	Conditions		min.	typ.	max.	Unit				
Inverse diode										
$V_F = V_{EC}$	I _F = 600 A	T _j = 25 °C		2.21	2.59	V				
	V _{GE} = 0 V chiplevel	T _j = 150 °C		2.29	2.74	V				
V _{F0}	chiplevel	T _j = 25 °C		1.33	1.53	V				
		T _j = 150 °C		1.03	1.13	V				
r _F	chiplevel	T _j = 25 °C		1.46	1.77	mΩ				
		T _j = 150 °C		2.1	2.7	mΩ				
I _{RRM}	I _F = 600 A	T _j = 150 °C		418		Α				
Q _{rr}	di/dt _{off} = 6400 A/μs V _{GE} = -15 V	T _j = 150 °C		82		μC				
E _{rr}	V _{CC} = 600 V	T _j = 150 °C		31		mJ				
R _{th(j-c)}	per diode	per diode			0.08	K/W				
R _{th(c-s)}	per diode (λ _{grease} =0.81 W/(m*K))			0.039		K/W				
R _{th(c-s)}	per diode, pre-applied phase change material			0.031		K/W				
Module						•				
L _{CE}				20		nΗ				
R _{CC'+EE'}	measured per	T _C = 25 °C		0.95		mΩ				
	switch	T _C = 125 °C		1.25		mΩ				
R _{th(c-s)1}	calculated without thermal coupling			0.009		K/W				
R _{th(c-s)2}	including thermal c T _s underneath mod (m*K))		0.014		K/W					
R _{th(c-s)2}	including thermal co T _s underneath mod phase change mate		0.011		K/W					
Ms	to heat sink (M5)		3		6	Nm				
Mt		to terminals (M6)	3		6	Nm				
						Nm				
w					350	g				
Temperat	ure Sensor									
R ₁₀₀	T _c =100°C (R ₂₅ =5 kΩ)			493 ± 5%		Ω				
B _{100/125}	$R_{(T)}=R_{100}exp[B_{100/125}(1/T-1/T_{100})]; T[K];$			3550 ±2%		К				

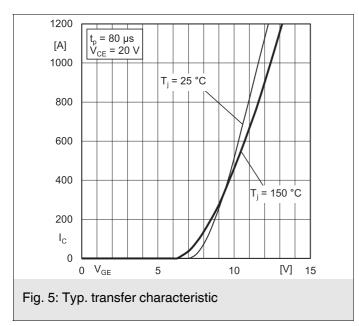


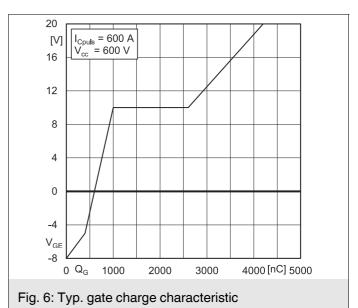


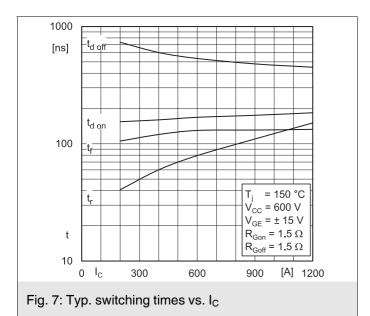


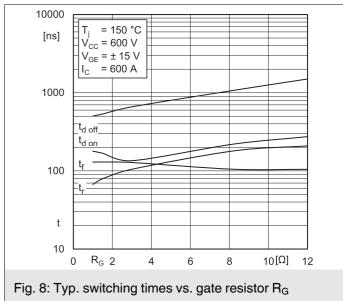


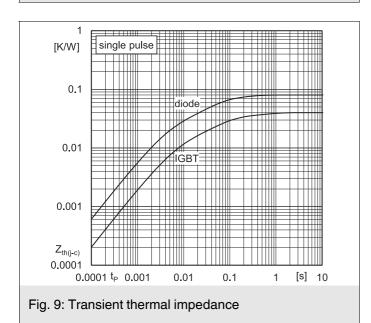


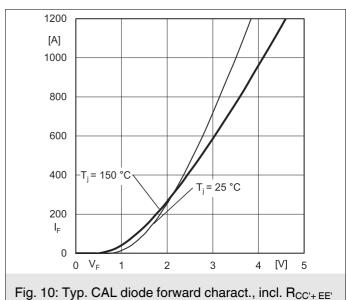


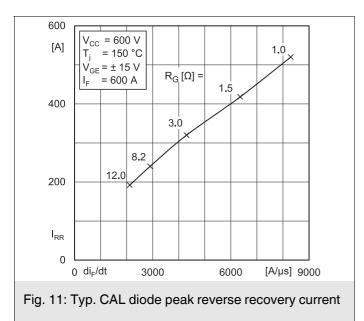


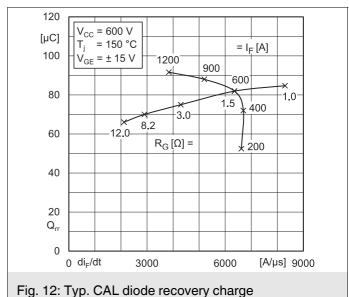


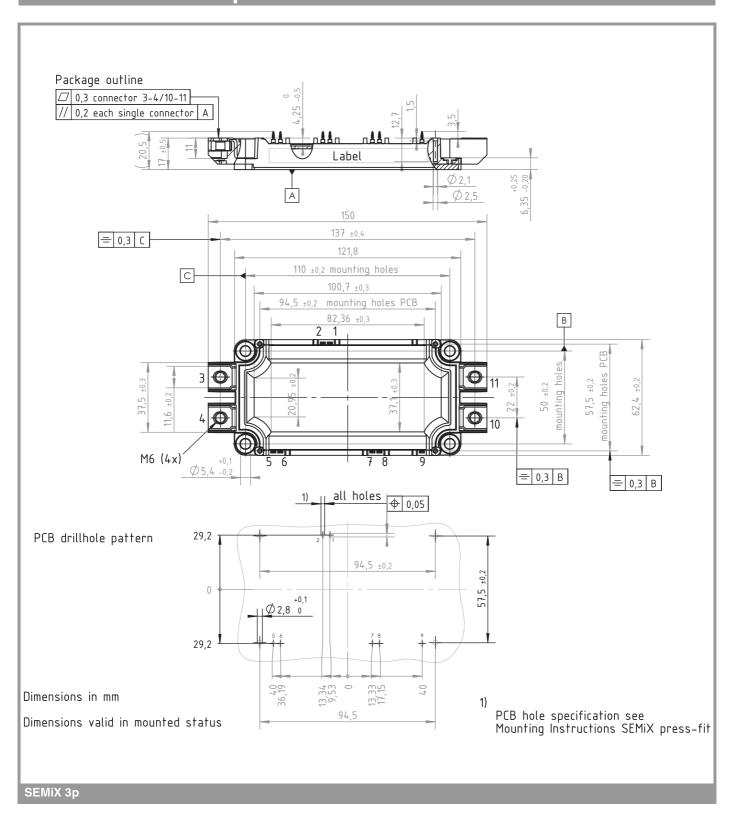












99 4 7 10/11 5 10/11 pinout

This is an electrostatic discharge sensitive device (ESDS) due to international standard IEC 61340.

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